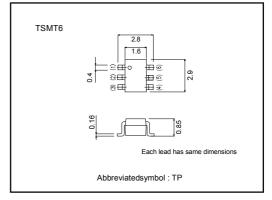
DC-DC Converter (-30V, -2.5A) RSQ025P03

Features

- 1) Low On-resistance.(120m Ω at 4.5V)
- 2) High Power Package.(PD=1.25W)
- 3) High speed switching.
- 4) Low voltage drive.(4V)

• External dimensions (Units : mm)



Applications

DC-DC converter

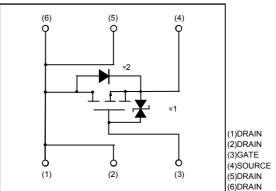
●Structure

Silicon P-channel MOSFET

Packaging specifications

Туре	Package	Taping		
	Code	TR		
	Basic ordering unit (pieces)	3000		
RSQ025P03		0		

Equivalent circuit



*1 ESD PROTECTION DIODE

*2 BODY DIODE

Transistor

●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Drain-source voltage		VDSS	-30	V	
Gate-source voltage		Vgss	<u>+20</u>	V	
Drain current	Continuous	lo	±2.5	А	
	Pulsed	DP	±10	A *1	
Source current (Body diode)	Continuous	ls	_1	А	
	Pulsed	Isp	-4	A *1	
Total power dissipation		PD	1.25	W*2	
Channel temperature		Tch	150	۵°	
Range of Storage temperature		Tstg	-55~+150	°C	

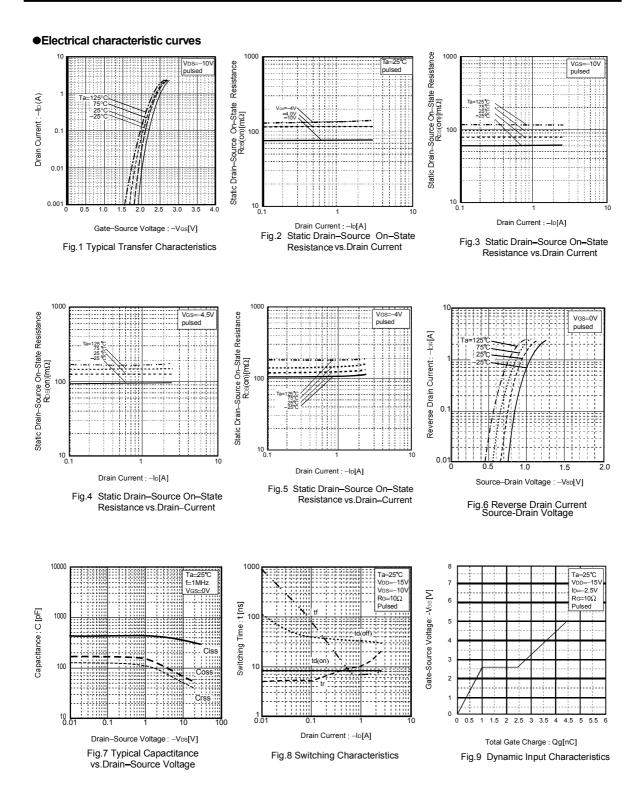
∗1 Pw≦10μs, Duty cycle≦1%

*2 Mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions		
Gate-source leakage	Igss	-	-	<u>+</u> 10	μΑ	Vgs=±20V, Vds=0V		
Drain-source breakdown voltage	V(BR)DSS	-30	-	-	V	ID=-1mA, VGs=0V		
Zero gate voltage drain current	IDSS	-	-	-1	μΑ	Vds=-30V, Vgs=0V		
Gate threshold voltage	VGS(th)	-1.0	-	-2.5	V	VDS=-10V, ID=-1mA		
Static drain-source on-state resistance	* RDS(on)	-	80	110	mΩ	ID=-2.5A, VGS=-10V		
		-	120	165	mΩ	ID=-1.25A, VGS=-4.5V		
		-	145	200	mΩ	ID=-1.25A, VGS=-4.0V		
Foward transfer admittance	Y _{fs} *	1.2	-	_	S	Vos=-10V, Io=-1.25A		
Input capacitance	Ciss	-	320	_	pF	VDS=-10V,VGS=0V f=1MHz		
Output capacitance	Coss	-	85	_	pF			
Reverse transfer capacitance	Crss	-	60	-	pF			
Turn-on delay time	td(on) *	-	8	-	ns	- ID=-1.25A VDD≑-15V VGS=-4.5V RL=12Ω RGS=10Ω		
Rise time	tr *	-	11	_	ns			
Turn-off delay time	td(off) *	-	33	-	ns			
Fall time	tr *	-	7	_	ns			
Total gate charge	Qg	-	4.4	-	nC	- V _{DD} ≒-15V V _{GS} =-5V - I _D =-2.5A		
Gate-source charge	Qgs	-	1.0	_	nC			
Gate-drain charge	Qgd	-	1.4	-	nC			
*PULSED Body diode characteristics (source-drain characteristics)								
Forward voltage	VSD	-	_	-1.2	V	Is=-0.9A, Vgs=0V		

Transistor



Measurement circuits

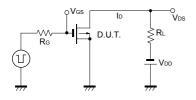


Fig.10 Switching Time Measurement Circuit

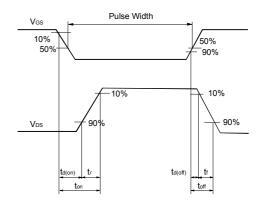


Fig.11 Switching Waveforms

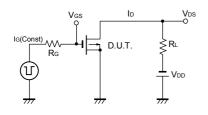


Fig.12 Gate Charge Measurement Circuit

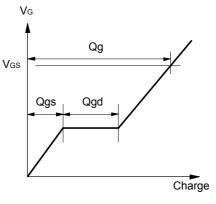


Fig.13 Gate Charge Waveforms

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